

# BRMMBT4403Q

Rev.B May.-2023

## / Descriptions

SOT-23          PNP          Silicon PNP transistor in a SOT-23 Plastic Package.

## / Features

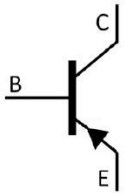
500mA          AEC-Q101

Collector currents up to 500 mA, Qualified to AEC-Q101 Standards for High Reliability, HF Product.

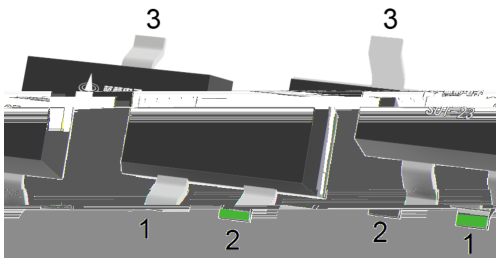
## / Applications

General purpose amplifier and switch requiring, Meet the stringent requirements of automotive applications.

## / Equivalent Circuit



## / Pinning



PIN 1   Base          PIN 2   Emitter          PIN 3   Collector

## / $h_{FE}$ Classifications & Marking

|                |           |
|----------------|-----------|
| $h_{FE}$ Range | 100   300 |
| Marking        | 2TQ       |

## / Absolute Maximum Ratings(Ta=25 )

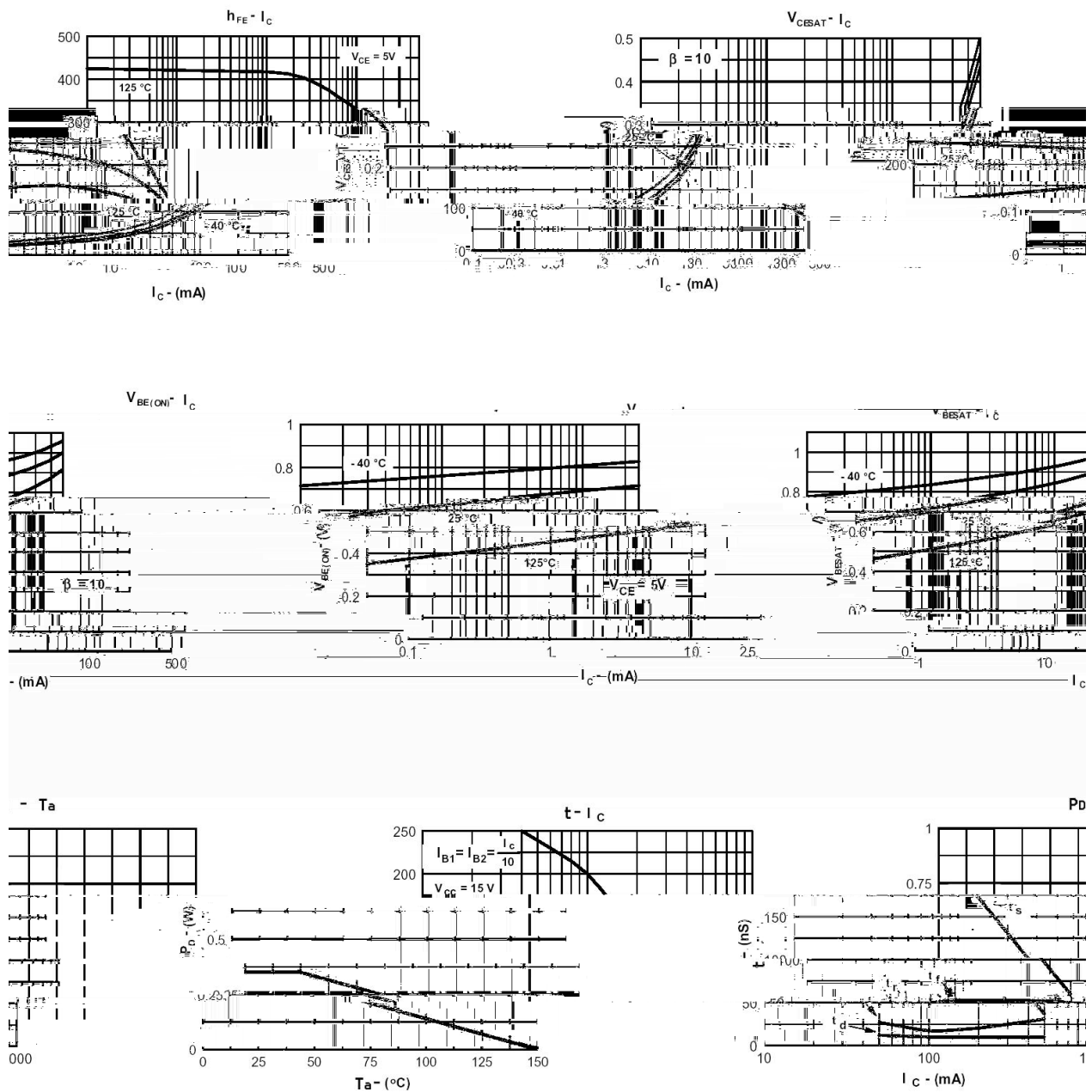
| Parameter                    | Symbol    | Rating  | Unit |
|------------------------------|-----------|---------|------|
| Collector to Base Voltage    | $V_{CBO}$ | -40     | V    |
| Collector to Emitter Voltage | $V_{CEO}$ | -40     | V    |
| Emitter to Base Voltage      | $V_{EBO}$ | -5.0    | V    |
| Collector Current            | $I_C$     | -600    | mA   |
| Collector Power Dissipation  | $P_C$     | 350     | mW   |
| Junction Temperature         | $T_j$     | 150     | °C   |
| Storage Temperature Range    | $T_{stg}$ | -55 150 | °C   |

## / Electrical Characteristics(Ta=25 )

| Parameter                              | Symbol            | Test Conditions                                             | Min   | Typ | Max   | Unit |
|----------------------------------------|-------------------|-------------------------------------------------------------|-------|-----|-------|------|
| Collector to Base Breakdown Voltage    | $V_{CBO}$         | $I_C = -0.1mA$ $I_E = 0$                                    | -40   |     |       | V    |
| Collector to Emitter Breakdown Voltage | $V_{CEO}$         | $I_C = -1.0mA$ $I_B = 0$                                    | -40   |     |       | V    |
| Emitter to Base Breakdown Voltage      | $V_{EBO}$         | $I_E = -0.1mA$ $I_C = 0$                                    | -5.0  |     |       | V    |
| Collector Cut-Off Current              | $I_{CBO}$         | $V_{CB} = -40V$ $I_E = 0$                                   |       |     | -50   | nA   |
| Emitter Cut-Off Current                | $I_{EBO}$         | $V_{EB} = -5.0V$ $I_C = 0$                                  |       |     | -50   | nA   |
| DC Current Gain                        | $h_{FE(1)}$       | $V_{CE} = -2.0V$ $I_C = -150mA$                             | 100   |     | 300   |      |
|                                        | $h_{FE(2)}$       | $V_{CE} = -1.0V$ $I_C = -0.1mA$                             | 30    |     |       |      |
|                                        | $h_{FE(3)}$       | $V_{CE} = -1.0V$ $I_C = -1.0mA$                             | 60    |     |       |      |
|                                        | $h_{FE(4)}$       | $V_{CE} = -1.0V$ $I_C = -10mA$                              | 100   |     |       |      |
|                                        | $h_{FE(5)}$       | $V_{CE} = -2.0V$ $I_C = -500mA$                             | 20    |     |       |      |
| Collector-Emitter Saturation voltage   | $V_{CE(sat) (1)}$ | $I_C = -150mA$ $I_B = -15mA$                                |       |     | -0.4  | V    |
|                                        | $V_{CE(sat) (2)}$ | $I_C = -500mA$ $I_B = -50mA$                                |       |     | -0.75 | V    |
| Base-Emitter Saturation Voltage        | $V_{BE(sat) (1)}$ | $I_C = -150mA$ $I_B = -15mA$                                | -0.75 |     | -0.95 | V    |
|                                        | $V_{BE(sat) (2)}$ | $I_C = -500mA$ $I_B = -50mA$                                |       |     | -1.3  | V    |
| Transition Frequency                   | $f_T$             | $V_{CE} = -10V$ $I_C = -20mA$<br>$f = 100MHz$               | 200   |     |       | MHz  |
| Delay Time                             | $t_d$             | $V_{CC} = -30V$ $I_C = -150mA$<br>$I_{B1} = -15mA$          |       |     | 15    | ns   |
| Rise Time                              | $t_r$             |                                                             |       |     | 20    | ns   |
| Storage Time                           | $t_s$             | $V_{CC} = -30V$ $I_C = -150mA$<br>$I_{B1} = I_{B2} = -15mA$ |       |     | 225   | ns   |
| Fall Time                              | $t_f$             |                                                             |       |     | 30    | ns   |



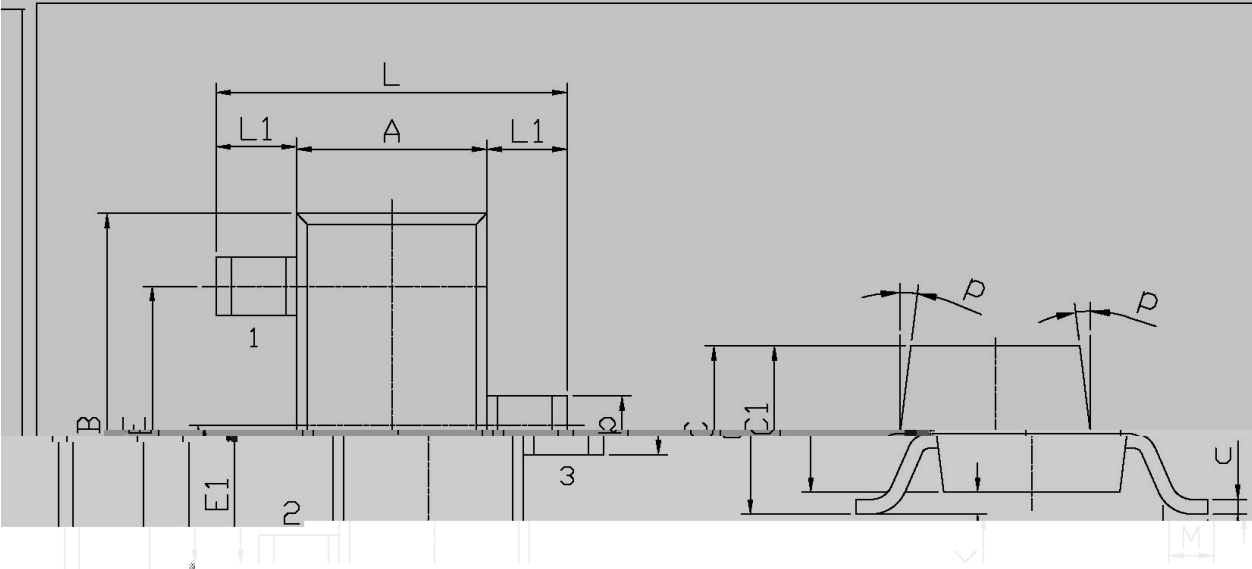
# Electrical Characteristic Curve



/ Package Dimensions

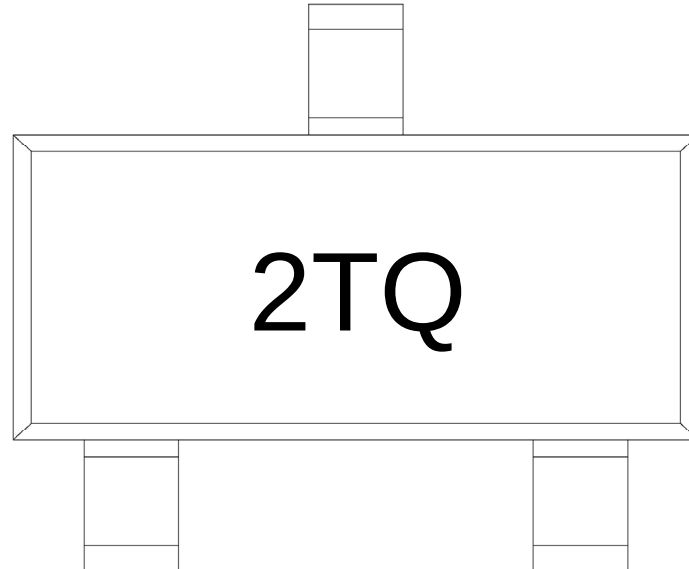
SOT-23

单位: mm



| Symbol | Dimensions in Millimeters |      | Symbol | Dimensions in Millimeters |      |
|--------|---------------------------|------|--------|---------------------------|------|
|        | Min                       | Max  |        | Min                       | Max  |
| L      | 2.2                       | 2.7  | C      | 1.30Max                   |      |
| L1     | 0.45                      | 0.65 | C1     | 0.90                      | 1.20 |
| A      | 1.15                      | 1.50 | c      | 0.05                      | 0.20 |
| B      | 2.70                      | 3.10 | K      | 0                         | 0.10 |
| E      | 1.70                      | 2.10 | M      | 0.20MIN                   |      |
| E1     | 0.95                      | 1.25 |        |                           |      |

**/ Marking Instructions**



2T

Q

Note:

2T      Product Type Code

Q:      Automobile halogen-free product Code

(     ) / Temperature Profile for IR Reflow Soldering(Pb-Free)

|  |
|--|
|  |
|  |
|  |
|  |
|  |
|  |
|  |

Note:

- 1

150    200

60    120sec;

1.Preheating:150~200    , Time:60~120sec.
- 2

255±5

5±0.5sec;

2.Peak Temp.:255±5    , Duration:5±0.5sec.
- 3

2    10

/sec.

3.Cooling Speed: 2~10    /sec.